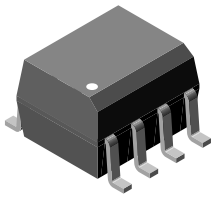
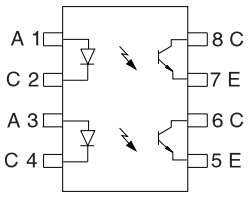
Optocoupler, Phototransistor Output, Dual Channel, SOIC-8 package



i179018



FEATURES

- Two channel coupler
- SOIC-8 surface mountable package
- Standard lead spacing of 0.05"
- Available only on tape and reel option (conforms to EIA standard 481-2)
- Isolation test voltage, 4000 V_{RMS}
- Compatible with dual wave, vapor phase and IR reflow soldering
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

DESCRIPTION

The ILD205T/206T/207T/211T/213T/217T are optically coupled pairs with a Gallium Arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD205T/206T/207T/211T/213T/217T come in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited space. In addition to eliminating through-holes requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high BV_{CEO} of 70 V gives a higher safety margin compared to the industry standard of 30 V.

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- CUL - file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-2 (VDE 0884) available with option 1

ORDER INFORMATION

PART	REMARKS
ILD205T	CTR 40 to 80 %, SOIC-8
ILD206T	CTR 63 to 125 %, SOIC-8
ILD207T	CTR 100 to 200 %, SOIC-8
ILD211T	CTR > 20 %, SOIC-8
ILD213T	CTR > 100 %, SOIC-8
ILD217T	CTR > 100 %, SOIC-8

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT				
Peak reverse voltage		V_R	6	V
Peak pulsed voltage	1 µs, 300 pps		1	A
Continuous forward current per channel			30	mA
Power dissipation		P_{diss}	50	mW
Derate linearly from 25 °C			0.66	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	70	V
Emitter collector breakdown voltage		BV_{ECO}	7	V
Power dissipation per channel		P_{diss}	125	mW
Derate linearly from 25 °C			1.67	mW/°C
COUPLER				
Isolation test voltage	t = 1 s	V_{ISO}	4000	V_{RMS}
Total package dissipation ambient (2 LEDs and 2 detectors, 2 channels)		P_{tot}	300	mW
Derate linearly from 25 °C			4	mW/°C
Storage temperature		T_{stg}	- 55 to + 150	°C
Operating temperature		T_{amb}	- 55 to + 100	°C
Soldering time from 260 °C (2)		T_{sld}	10	s

Notes

(1) T_{amb} = 25 °C, unless otherwise specified.
Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

(2) Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTCS							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT							
Forward voltage	I_F = 10 mA		V_F		1.2	1.55	V
Reverse current	V_R = 6 V		I_R		0.1	100	µA
Capacitance	V_R = 0 V		C_O		25		pF
OUTPUT							
Collector emitter breakdown voltage	I_C = 10 µA		BV_{CEO}	70			V
Emitter collector breakdown voltage	I_E = 10 µA		BV_{ECO}	7			V
Collector emitter leakage current	V_{CE} = 10 V, I_F = 0 A		I_{CEO}		5	50	nA
Collector emitter capacitance	V_{CE} = 0 V		C_{CE}		10		pF
COUPLER							
Collector emitter saturation voltage	I_F = 10 mA, I_C = 2.5 mA		V_{CEsat}			0.4	V
Capacitance (input to output)			C_{IO}		0.5		pF
Resistance (input to output)			R_{IO}		100		GΩ

Note

T_{amb} = 25 °C, unless otherwise specified.
Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
DC current transfer ratio	V_{CE} = 5 V, I_F = 10 mA	ILD205T	CTR_{DC}	40		80	%
		ILD206T	CTR_{DC}	63		125	%
		ILD207T	CTR_{DC}	100		200	%
		ILD211T	CTR_{DC}	20			%
		ILD213T	CTR_{DC}	100			%
	V_{CE} = 5 V, I_F = 1.0 mA	ILD205T	CTR_{DC}	13	30		%
		ILD206T	CTR_{DC}	22	45		%
		ILD207T	CTR_{DC}	34	70		%
		ILD217T	CTR_{DC}	100	120		%

SWITCHING CHARACTERISTICS							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Turn-on time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 5 V		t_{on}	5			µs
Turn-off time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 5 V		t_{off}	4			µs

SAFETY AND INSULATION RATINGS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V_{IOTM}			6000			V
V_{IORM}			560			V
P_{SO}					350	mW
I_{SI}					150	mA
T_{SI}					165	°C
Creepage			4			mm
Clearance			4			mm
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.2			mm

Note

As per IEC60747-5-2, §7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

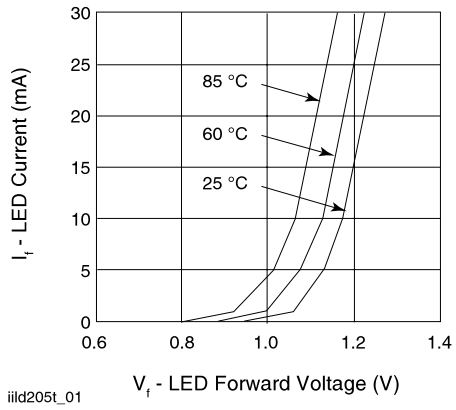


Fig. 1 - Forward Current vs. Forward Voltage

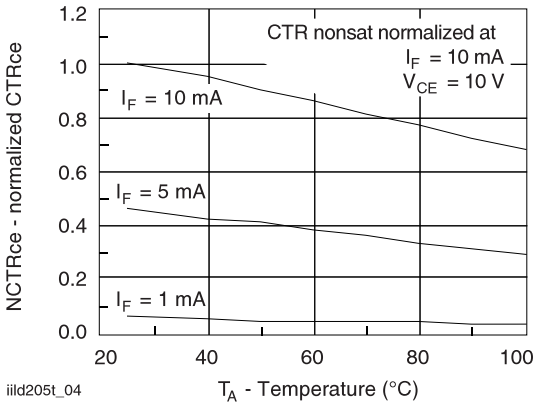


Fig. 4 - Current Transfer Ratio (normalized) vs. Ambient Temperature

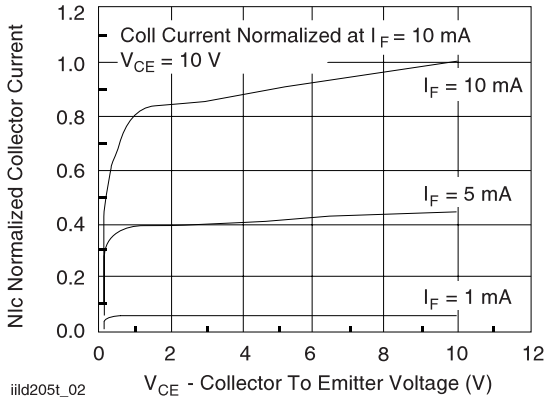


Fig. 2 - Collector Emitter Current vs. V_{CE}

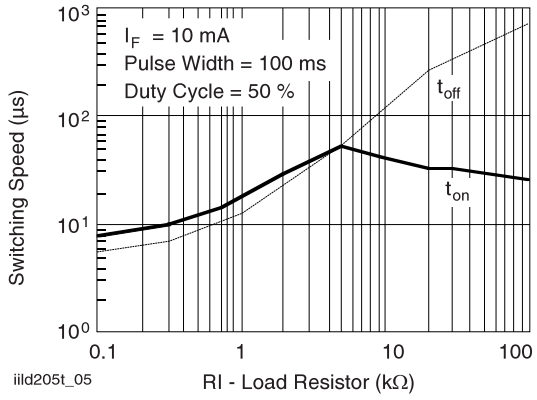


Fig. 5 - Switching Speed vs. Load Resistor

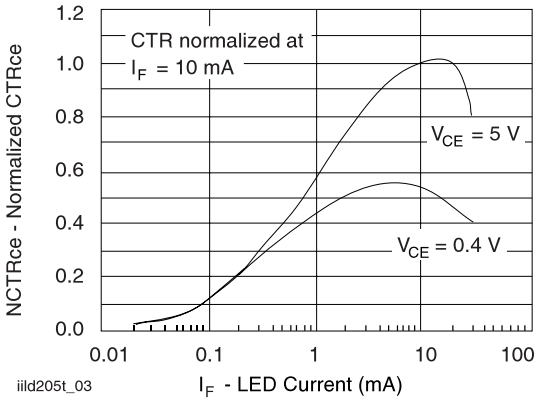


Fig. 3 - Normalized CTR_{CE} vs. Forward Current

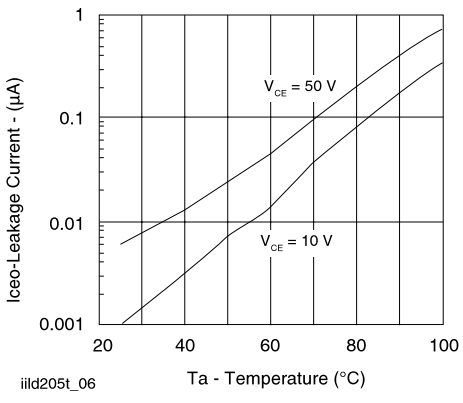


Fig. 6 - Collector Current vs. Ambient Temperature

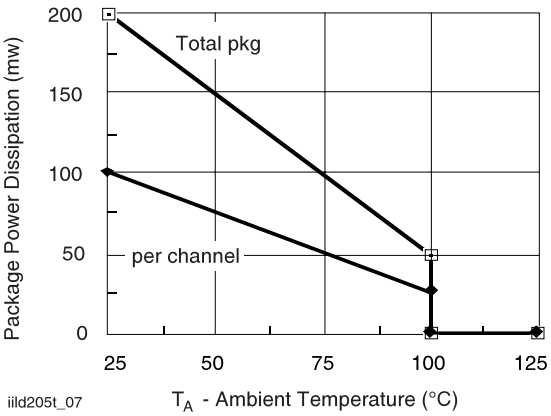


Fig. 7 - Power Dissipation vs. Ambient Temperature

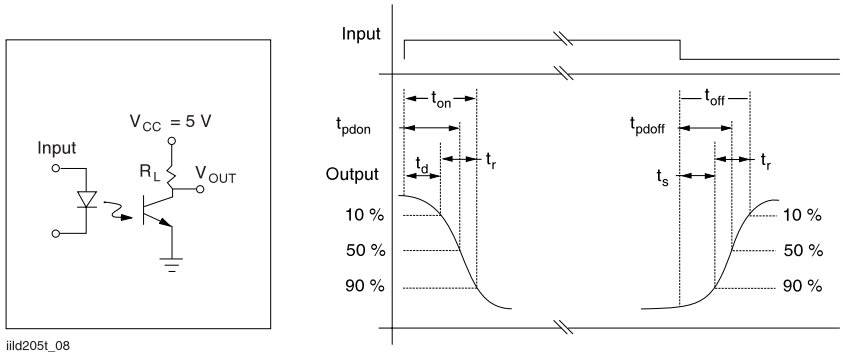
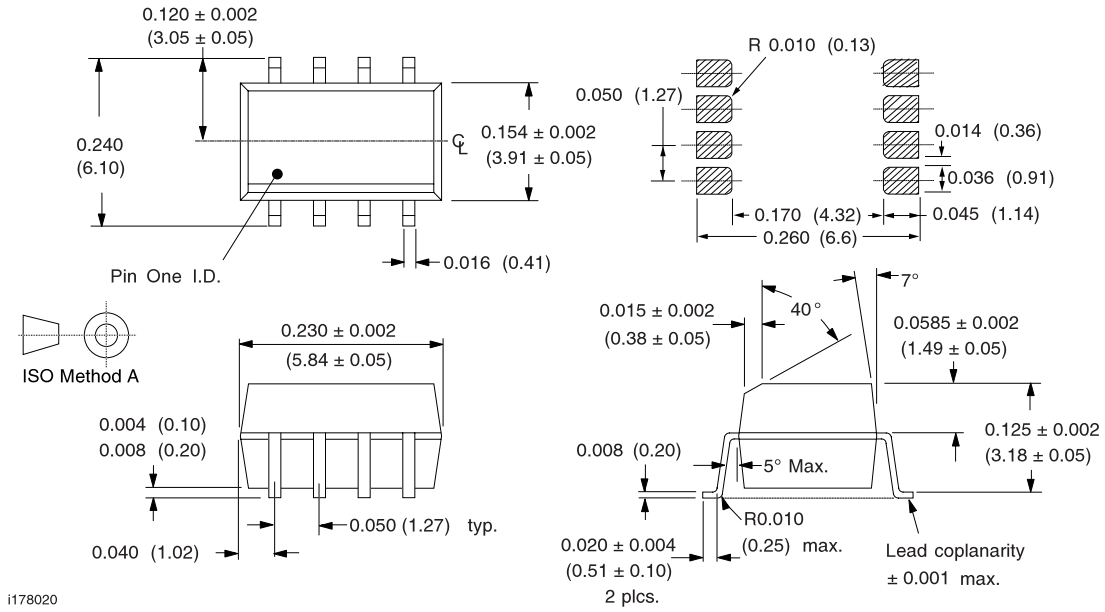


Fig. 8 Switching Test Circuit

PACKAGE DIMENSIONS in inches (millimeters)



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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